LM4001G THRU LM4007G

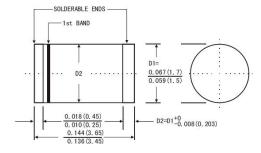
SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIERS

Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

Features

- The plastic package carries Underwrites Laboratory Flammability classification 94V-0
- · For surface mounted application
- · Glass passivated junction



MiniMELF (DO-213AA) Plastic Package

Mechanical Data

• Case: MiniMELF(DO-213AA), molded plastic body

 Terminals: Lead solderable per MIL-STD-750, method 2026

• Polarity: Color band denotes cathode end

• Mounting Position: Any

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Parameter | Symbols | LM4001G | LM4002G | LM4003G | LM4004G | LM4005G | LM4006G | LM4007G | Units |
|--|-------------------|---------------|---------|---------|---------|---------|---------|---------|-------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | V _{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current at T _A = 75 °C | I _(AV) | 1 | | | | | | | Α |
| Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) | I _{FSM} | 25 | | | | | | А | |
| Maximum Forward Voltage at 1 A | V _F | 1.1 | | | | | | V | |
| $ \begin{array}{ll} \text{Maximum Reverse Current} & \text{$T_{A} = 25 ^{\circ}\text{C}$} \\ \text{at Rated DC Blocking Voltage} & \text{$T_{A} = 125 ^{\circ}\text{C}$} \end{array} $ | I _R | 5 50 | | | | | | μA | |
| Typical Junction Capacitance 1) | CJ | 15 | | | | | | pF | |
| Typical Thermal Resistance 2) | $R_{\theta JA}$ | 75 | | | | | | °C/W | |
| Typical Thermal Resistance 3) | $R_{\theta JL}$ | 30 | | | | | | °C/W | |
| Operating and Storage Temperature Range | T_j, T_{stg} | - 65 to + 175 | | | | | | °C | |

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V D.C



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Dated: 10/12/2008 N

²⁾ Thermal resistance from junction to ambient, 0.24 X 0.24" (6 X 6 mm) copper pads to each terminal

³⁾ Thermal resistance from junction to terminal, 0.24 X 0.24" (6 X 6 mm) copper pads to each terminal

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

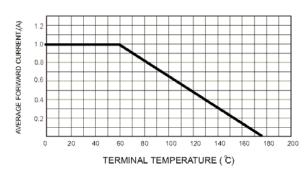


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

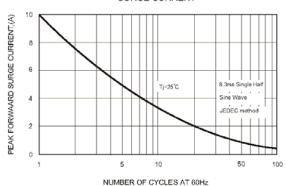


FIG.4-TYPICAL JUNCTION CAPACITANCE

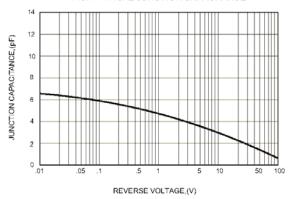


FIG.2-TYPICAL FORWARD

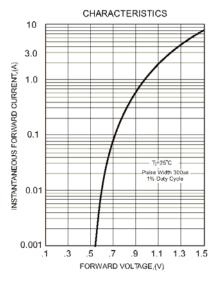
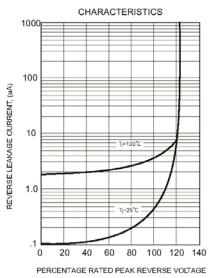


FIG.5 - TYPICAL REVERSE





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